Low Distortion, Precision, Wide Bandwidth Op Amp

AD9617

FEATURES
Usable Closed-Loop Gain Range: ±1 to ±40
Low Distortion: −67 dBc (2nd) at 20 MHz
Small Signal Bandwidth: 190 MHz (AV = +3)
Large Signal Bandwidth: 150 MHz at 4 V p-p
Settling Time: 10 ns to 0.1%; 14 ns to 0.02%
Overdrive and Output Short Circuit Protected
Fast Overdrive Recovery
DC Nonlinearity 10 ppm

APPLICATIONS
Driving Flash Converters
D/A Current-to-Voltage Converters
IF, Radar Processors
Baseband and Video Communications
Photodiode, CCD Preamps

GENERAL DESCRIPTION
The AD9617 is a current feedback amplifier which utilizes a proprietary architecture to produce superior distortion and dc precision. It achieves this along with fast settling, very fast slew rate, wide bandwidth (both small signal and large signal) and exceptional signal fidelity. The device achieves −67 dBc 2nd harmonic distortion at 20 MHz while maintaining 190 MHz small signal and 150 MHz large signal bandwidths.

These attributes position the AD9617 as an ideal choice for driving flash ADCs and buffering the latest generation of DACs. Optimized for applications requiring gain between ±1 to ±15, the AD9617 is unity gain stable without external compensation.

Additional benefits of the AD9617B and T grades include input offset voltage of 500 µV and temperature coefficient (TC) of 3 µV/°C. These accuracy performance levels make the AD9617 an excellent choice for driving emerging high resolution (12–16 bits), high speed analog-to-digital converters and flash converters.

The AD9617 offers outstanding performance in high fidelity, wide bandwidth applications in instrumentation ranging from network and spectrum analyzers to oscilloscopes, and in military systems such as radar, SIGINT and ESM systems. The superior slew rate, low overshoot and fast settling of the AD9617 allow the device to be used in pulse applications such as communications receivers and high speed ATE. Most monolithic op amps suffer in these precision pulse applications due to slew rate limiting.

The AD9617J operates over the range of 0°C to +70°C and is available in either an 8-pin plastic mini-DIP or an 8-lead plastic small outline package (SOIC). The AD9617A and B versions are rated over the industrial temperature range of −40°C to +85°C. The AD9617S and T versions are rated over the military temperature range of −55°C to +125°C and are available processed to MIL-STD-883B.
### DC ELECTRICAL CHARACTERISTICS

(Unless otherwise noted, \( A_V = +3; \) \( \pm V_S = \pm 5 \, V; \) \( R_F = 400 \, \Omega; \) \( R_{LOAD} = 100 \, \Omega)\)

<table>
<thead>
<tr>
<th>Parameter</th>
<th>Conditions</th>
<th>Temp</th>
<th>Test Level</th>
<th>AD9617JN/JR</th>
<th>AD9617AQ/SQ</th>
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<tr>
<td></td>
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<td></td>
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<td></td>
<td>Min</td>
<td>Typ</td>
<td>Max</td>
<td>Min</td>
</tr>
<tr>
<td>Input Offset Voltage (^3)</td>
<td></td>
<td>+25°C</td>
<td>I</td>
<td>-1.1</td>
<td>+0.5</td>
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<td>Input Offset Voltage TC (^3)</td>
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<td>Full</td>
<td>IV</td>
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<td>+3</td>
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<td>+50</td>
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<td></td>
<td>Noninverting</td>
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<td>I</td>
<td>-25</td>
<td>+5</td>
<td>+35</td>
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<td>+30</td>
<td>+125</td>
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<tr>
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<td>-50</td>
<td>+50</td>
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<td>1.5 pF</td>
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<td>Common-Mode Input Range (^6)</td>
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<td>±1.4</td>
<td>±1.5</td>
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<tr>
<td></td>
<td>T = T (_{\text{MIN}}) to +25°C</td>
<td>Full</td>
<td>II</td>
<td>±1.7</td>
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<td>Common-Mode Rejection Ratio (^7)</td>
<td>T = T (_{\text{MIN}}) to +25°C</td>
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<td>44</td>
<td>48</td>
<td>44</td>
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<td>Power Supply Rejection Ratio</td>
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<td>50</td>
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<td>Open Loop Gain</td>
<td>( T_0 )</td>
<td>At DC</td>
<td>+25°C</td>
<td>V</td>
<td>500</td>
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<td>Nonlinearity</td>
<td>At DC</td>
<td>+25°C</td>
<td>IV</td>
<td>10</td>
<td>10</td>
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<td>Output Voltage Range</td>
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<td>Output Impedance</td>
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<td>T = T (_{\text{MIN}})</td>
<td>II</td>
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<td>50</td>
<td>50 mA</td>
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### AC ELECTRICAL CHARACTERISTICS

(Unless otherwise noted, \( A_V = +3; \) \( \pm V_S = \pm 5 \, V; \) \( R_F = 400 \, \Omega; \) \( R_{LOAD} = 100 \, \Omega)\)

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<td></td>
<td></td>
<td>Min</td>
<td>Typ</td>
<td>Max</td>
<td>Min</td>
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### ABSOLUTE MAXIMUM RATINGS \(^1\)

- Supply Voltages (±\( V_S \)): +7 V
- Common-Mode Input Voltage: ±\( V_S \)
- Differential Input Voltage: 3 V
- Continuous Output Current: 70 mA
- Operating Temperature Ranges:
  - AD9617JN/JR: 0°C to +70°C
  - AD9617AQ/BQ: −40°C to +85°C
  - AD9617SQ/TQ: −55°C to +125°C

1. Exception: \( V_S = \pm 5 \, V; \) \( V_F = 10 \, V; \) \( R_{LOAD} = 100 \, \Omega)\)
2. 70 mA: \( V_F = 10 \, V; \) \( R_{LOAD} = 100 \, \Omega)\)
3. Junction Temperature
4. Storage Temperature
5. Lead Soldering Temperature (10 Seconds)
6. Current
7. Temperature
8. Voltage
9. Frequency
10. Phase
11. Degree
12. pA/°C
13. nV/√Hz
14. mA
15. kHz
16. Ω
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<th>Parameter</th>
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<td></td>
<td>Min</td>
<td>Typ</td>
<td>Max</td>
<td>Min</td>
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<tr>
<td><strong>TIME DOMAIN</strong></td>
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<tr>
<td>Slew Rate</td>
<td>( V_{\text{OUT}} = 4 \text{ V Step} )</td>
<td>Full</td>
<td>IV</td>
<td>1400</td>
<td></td>
<td>1100</td>
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<tr>
<td>Rise/Fall Time</td>
<td>( V_{\text{OUT}} = 4 \text{ V Step} )</td>
<td>T = +25°C to T(_{\text{MAX}}) ←</td>
<td>IV</td>
<td>2.0</td>
<td></td>
<td>2.0</td>
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<tr>
<td></td>
<td>( V_{\text{OUT}} = 4 \text{ V Step} )</td>
<td>T = T(_{\text{MIN}}) ←</td>
<td>IV</td>
<td>2.4</td>
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<td>Overshoot</td>
<td>( V_{\text{OUT}} = 2 \text{ V Step} )</td>
<td>Full</td>
<td>IV</td>
<td>3</td>
<td></td>
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<td>Settling Time</td>
<td>To 0.1%</td>
<td>( V_{\text{OUT}} = 2 \text{ V Step} )</td>
<td>Full</td>
<td>IV</td>
<td>10</td>
<td></td>
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<tr>
<td></td>
<td>To 0.02%</td>
<td>( V_{\text{OUT}} = 2 \text{ V Step} )</td>
<td>Full</td>
<td>IV</td>
<td>14</td>
<td></td>
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<tr>
<td></td>
<td>To 0.1%</td>
<td>( V_{\text{OUT}} = 4 \text{ V Step} )</td>
<td>Full</td>
<td>IV</td>
<td>11</td>
<td></td>
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<tr>
<td></td>
<td>To 0.02%</td>
<td>( V_{\text{OUT}} = 4 \text{ V Step} )</td>
<td>Full</td>
<td>IV</td>
<td>16</td>
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<tr>
<td>2(x) Overdrive Recovery to ( \pm 2 \text{ mV of Final Value} )</td>
<td>( V_{\text{IN}} = 1.7 \text{ V Step} )</td>
<td>+25°C</td>
<td>V</td>
<td>50</td>
<td></td>
<td>50</td>
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<td>Propagation Delay</td>
<td>+25°C</td>
<td>V</td>
<td>2</td>
<td></td>
<td>2</td>
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<tr>
<td>Differential Gain(^8)</td>
<td>Full</td>
<td>V</td>
<td>&lt;0.01</td>
<td></td>
<td>&lt;0.01</td>
<td></td>
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<tr>
<td>Differential Phase(^8)</td>
<td>Full</td>
<td>V</td>
<td>0.01</td>
<td></td>
<td>0.01</td>
<td></td>
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<tr>
<td><strong>POWER SUPPLY REQUIREMENTS</strong></td>
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<td></td>
</tr>
<tr>
<td>Quiescent Current</td>
<td>( +I_{\text{S}} )</td>
<td>Full</td>
<td>II</td>
<td>34</td>
<td>48</td>
<td></td>
</tr>
<tr>
<td></td>
<td>( -I_{\text{S}} )</td>
<td>Full</td>
<td>II</td>
<td>34</td>
<td>48</td>
<td></td>
</tr>
</tbody>
</table>

**NOTES**

1. Absolute maximum ratings are limiting values to be applied individually and beyond which the serviceability of the circuit may be impaired. Functional operability is not necessarily implied. Exposure to absolute maximum rating conditions for an extended period of time may affect device reliability.
2. Output is short circuit protected to ground, but not to supplies. Continuous short circuit to ground may affect device reliability.
3. Typical thermal impedances (part soldered onto board):
   - Mini-DIP: \( \theta_{JA} = 140°C/W; \theta_{JC} = 30°C/W. \) Side Brazed/Cerdip: \( \theta_{JA} = 110°C/W; \theta_{JC} = 20°C/W. \) SOIC Package: \( \theta_{JA} = 150°C/W; \theta_{JC} = 30°C/W. \)
4. Measured with respect to the inverting input.
5. Typical is defined as the mean of the distribution.
6. Measured in voltage follower configuration.
7. Measured with \( V_{\text{IN}} = +0.25 \text{ V}. \)
8. Frequency = 4.3 MHz; \( R_{L} = 150 \Omega; AV = +3. \)

Specifications subject to change without notice.

**EXPLANATION OF TEST LEVELS**

**Test Level**

I - 100% production tested.

II - 100% production tested at +25°C and sample tested at specified temperatures. AC testing of J grade devices done on sample basis.

III - Sample tested only.

IV - Parameter is guaranteed by design and characterization testing.

V - Parameter is a typical value only.

VI - All devices are 100% production tested at +25°C. 100% production tested at temperature extremes for extended temperature devices; sample tested at temperature extremes for commercial/industrial devices.

**DIE CONNECTIONS**

**ORDERING GUIDE**

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<th>Model</th>
<th>Temperature Range</th>
<th>Package Description</th>
<th>Package Option</th>
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<td>AD9617JN</td>
<td>0 to +70°C</td>
<td>Plastic DIP</td>
<td>N-8</td>
</tr>
<tr>
<td>AD9617JR</td>
<td>0 to +70°C</td>
<td>SOIC</td>
<td>R-8</td>
</tr>
<tr>
<td>AD9617AQ</td>
<td>-40°C to +85°C</td>
<td>Cerdip</td>
<td>Q-8</td>
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<td>AD9617BQ</td>
<td>-40°C to +85°C</td>
<td>Cerdip</td>
<td>Q-8</td>
</tr>
<tr>
<td>AD9617SQ</td>
<td>-55°C to +125°C</td>
<td>Cerdip</td>
<td>Q-8</td>
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<tr>
<td>AD9617TQ</td>
<td>-55°C to +125°C</td>
<td>Cerdip</td>
<td>Q-8</td>
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THEORY OF OPERATION

The AD9617 has been designed to combine the key attributes of traditional “low frequency” precision amplifiers with exceptional high frequency characteristics that are independent of closed-loop gain. Previous “high frequency” closed-loop amplifiers have low open loop gain relative to precision amplifiers. This results in relatively poor dc nonlinearity and precision, as well as excessive high frequency distortion due to open loop gain rolloff.

Operational amplifiers use two basic types of feedback correction, each with advantages and disadvantages. Voltage feedback topologies exhibit an essentially constant gain bandwidth product. This forces the closed-loop bandwidth to vary inversely with closed-loop gain. Moreover, this type design typically slew rate limits in a way that causes the large signal bandwidth to be much lower than its small signal characteristics.

A newer approach is to use current feedback to realize better dynamic performance. This architecture provides two key attributes over voltage feedback configurations: (1) avoids slew rate limiting and therefore large signal bandwidth can approach small signal performance; and (2) low bandwidth variation versus gain settings, due to the inherently low open loop inverting input resistance (Rs).

The AD9617 uses a new current feedback topology that overcomes these limitations and combines the positive attributes of both current feedback and voltage feedback designs. These devices achieve excellent high frequency dynamics (slew, BW and distortion) along with excellent low frequency linearity and good dc precision.

DC GAIN CHARACTERISTICS

A simplified equivalent schematic is shown below. When operating the device in the inverting mode, the input signal error current (Ie) is amplified by the open loop transimpedance gain (To). The output signal generated is equal to To×Ie. Negative feedback is applied through RF such that the device operates at a gain (G) equal to −RF/Rf.

Noninverting operation is similar, with the input signal applied to the high impedance buffer (noninverting) input. As before, an output (buffer) error current (Ie) is generated at the low impedance inverting input. The signal generated at the output is fed back to the inverting input such that the external gain is (1+RF/Rf). The feedback mechanics are identical to the voltage feedback topology when exact equations are used.

The major difference lies in the front end architecture. A voltage feedback amplifier has symmetrical high resistance (buffered) inputs. A current feedback amplifier has a high noninverting resistance (buffered) input and a low inverting (buffer output) input resistance. The feedback mechanics can be easily developed using current feedback and transresistance open loop gain T(s) to describe the I/O relationship. (See typical specification chart.)

DC closed-loop gain for the AD9617 can be calculated using the following equations:

\[ G = \frac{V_O}{V_I} = \frac{-R_F}{1 + 1/LG} \]  \hspace{1cm} \text{inverting} (1)

\[ G = \frac{V_O}{V_N} = \frac{1 + R_F}{1 + 1/LG} \]  \hspace{1cm} \text{noninverting} (2)

where \( \frac{1}{LG} = \frac{R_S (R_F + R_S || R_f)}{T(s) || R_S || R_f} \) (3)

Because the noninverting input buffer is not ideal, input resistance Rs (at dc) is gain dependent and is typically higher for noninverting operation than for inverting operation. Rs will approach the same value (≈7 Ω) for both at input frequencies above 50 MHz. Below the open loop corner frequency, the noninverting Rs can be approximated as:

\[ R_S \text{ (noninverting)} = 7 + \frac{T(s)}{A_O} = 7 + \frac{T_O}{A_O} \] (4)

where: \( A_O = \text{Open Loop Voltage Gain} \approx G \times 600 \)

Inverting Rs below the open loop corner frequency can be approximated as:

\[ R_S \text{ (inverting)} = 7 + \frac{T(s)}{A_O} = 7 + \frac{T_O}{A_O} \] (5)

where: \( A_O = 40,000 \).

The AD9617 approaches this condition. With \( T_O = 1 \times 10^6 \) Ω, \( R_f = 500 \) Ω and \( R_S = 25 \) Ω (dc), a gain error no greater than 0.05% typically results for \( G = -1 \) and 0.15% for \( G = -40 \).

Moreover, the architecture linearizes the open loop gain over its operating voltage range and temperature resulting in ≥16 bits of linearity.

![Equivalent Circuit](image)

**DC Nonlinearity vs. VOUT**
AC GAIN CHARACTERISTICS

Closed-loop bandwidth at high frequencies is determined primarily by the roll-off of T(s). But circuit layout is critical to minimize external parasitics which can degrade performance by causing premature peaking and/or reduced bandwidth.

The inverting and noninverting dynamic characteristics are similar. When driving the noninverting input, the inverting input capacitance (Ci) will cause the noninverting closed-loop bandwidth to be higher than the inverting bandwidth for gains less than two (2). In the remaining cases, inverting and noninverting responses are nearly identical.

For best overall dynamic performance, the value of the feedback resistor (RF) should be 400 ohms. Although bandwidth reduces as closed-loop gain increases, the change is relatively small due to low equivalent series input impedance, ZS. (See typical performance charts.) The simplified equations governing the device's dynamic performance are shown below.

Closed-Loop Gain vs. Frequency:

\[ \frac{V_O}{V_I} \approx \frac{1 + RF}{RI} + 1 \]  

where: \( \tau = RF \times CG = 0.9 \text{ ns} \) (RF = 400 Ω)

\[ \text{Slew Rate} = \frac{\Delta V_O}{RF KCG} \times e^{-\tau/RF KCG} \]  

where: \( K = 1 + \frac{RS}{RI} \)

Increasing Bandwidth at Low Gains

By reducing RF, wider bandwidth and faster pulse response can be attained beyond the specified values, although increased overshoot, settling time and possible ac peaking may result. As a rule of thumb, overshoot and bandwidth will increase by 1% and 8%, respectively, for a 5% reduction in RF at gains of ±10. Lower gains will increase these sensitivities.

Equations 6 and 7 are simplified and do not accurately model the second order (open loop) frequency response term which is the primary contributor to overshoot, peaking and nonlinear bandwidth expansion. (See Open Loop Bode Plots.) The user should exercise caution when selecting RF values much lower than 400 Ω. Note that a feedback resistor must be used in all situations, including those in which the amplifier is used in a noninverting unity gain configuration.

Increasing Bandwidth at High Gains

Closed-loop bandwidth can be extended at high closed loop gain by reducing RF. Bandwidth reduction is a result of the feedback current being split between RS and RI. As the gain increases (for a given RF), more feedback current is shunted through RS, which reduces closed loop bandwidth (see Equation 6). To maintain specified BW, the following equations can be used to approximate RF and RI for any gain from ±1 to ±15.

\[ RF = 424 \pm 8 G \]  

(9)

\[ RI = \frac{424 \pm 8 G}{G-1} \]  

(10)

(9) and (10) represent inverting and noninverting responses.

\[ G = \text{Closed Loop Gain.} \]

Bandwidth Reduction

The closed loop bandwidth can be reduced by increasing RF. Equations 6 and 7 can be used to determine the closed loop bandwidth for any value of RF. Do not connect a feedback capacitor across RF, as this will degrade dynamic performance and possibly induce oscillation.

DC Precision and Noise

Output offset voltage results from both input bias currents and input offset voltage. These input errors are multiplied by the noise gain term \((1 + RF/RI)\) and algebraically summed at the output as shown below.

\[ V_O = V_{IO} \times \left(1 + \frac{RF}{RI}\right) \pm IBn \times RN \times \frac{1 + RF}{RI} \pm IBi \times RF \]  

(11)

Since the inputs are asymmetrical, IBi and IBn do not correlate. Canceling their output effects by making RN = RF will not reduce output offset errors, as it would for voltage feedback amplifiers. Typically, IBn is 5 μA and VIO is +0.5 mV (I sigma = 0.3 mV), which means that the dc output error can be reduced by making RN = 100 Ω. Note that the offset drift will not change significantly because the IBn TC is relatively small. (See specification table.)

The effective noise at the output of the amplifier can be determined by taking the root sum of the squares of Equation 11 and applying the spectral noise values found in the typical graph section. This applies to noise from the op amp only. Note that both the noise figure and equivalent input offset voltages im-
prove as the closed loop gain is increased (by keeping $R_F$ fixed and reducing $R_I$ with $R_N = 0 \, \Omega$).

![Capacitive Load Figure]

**Capacitive Load Considerations**
Due to the low inverting input resistance ($R_S$) and output buffer design, the AD9617 can directly handle input and/or output load capacitances of up to 20 pF. See the chart below.

**Input/Output Capacitance Comparisons**
A small series resistor can be used at the output of the amplifier and outside of the feedback loop to facilitate driving larger capacitive loads or for obtaining faster settling time. For capacitive loads above 20 pF, $R_{\text{SERIES}}$ should be considered.

![Recommended $R_{\text{SERIES}}$ vs. CL]

**APPLYING THE AD9617**
The superior frequency and time domain specifications of the AD9617 make it an obvious choice for driving flash converters and buffering the outputs of high speed DACs. Its outstanding distortion and noise performance make it well suited as a driver for analog to digital converters (ADCs) with resolutions as high as 16 bits.

Typical circuits for inverting and noninverting applications are shown in Figures 1 and 2.

Closed-loop gain for noninverting configurations is determined by the value of $R_I$ according to the equation:

$$ G = 1 + \frac{R_F}{R_I} $$

(L12)

![Figure 1. Noninverting Operation](https://example.com/fig1)

![Figure 2. Inverting Operation](https://example.com/fig2)

**LAYOUT CONSIDERATIONS**
As with all high performance amplifiers, printed circuit layout is critical in obtaining optimum results with the AD9617. The ground plane in the area of the amplifier should cover as much of the component side of the board as possible. Each power supply trace should be decoupled close to the package with at least a 3.3 µF tantalum and a low inductance, 0.1 µF ceramic capacitor.

All lead lengths for input, output and the feedback resistor should be kept as short as possible. All gain setting resistors should be chosen for low values of parasitic capacitance and inductance, i.e., microwave resistors and/or carbon resistors. Stripline techniques should be used for lead lengths in excess of one inch. Sockets should be avoided if possible because of their stray inductance and capacitance. If sockets are necessary, individual pin sockets such as AMP p/n 6-330808-3 should be used. These contribute far less stray reactance than molded socket assemblies.

An evaluation board is available from Analog Devices at nominal cost.

*Consult factory regarding MIL-883 parts in “Z” packages.*
Typical Performance (AV = +3; ±V5 = ±5 V; RF = 400 V, unless otherwise noted)
OUTLINE DIMENSIONS
Dimensions shown in inches and (mm).

Suffix JR

Suffixes AQ/BQ/SQ/TQ

Side-Brazed Package May Be Substituted for Model Suffixes AQ/BQ/SQ/TQ

Suffix JN

NOTE
LEAD NO. 1 IDENTIFIED BY DOT OR NOTCH

AD9617

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